TOSHIBA

TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC74LCX157F,TC74LCX157FN,TC74LCX157FT,TC74LCX157FK

Low Voltage Quad 2-Channel Multiplexer with 5 V Tolerant Inputs and Outputs

The TC74LCX157 is a high-performance CMOS multiplexer. Designed for use in 3.3-V systems, it achieves high-speed operation while maintaining the CMOS low power dissipation.

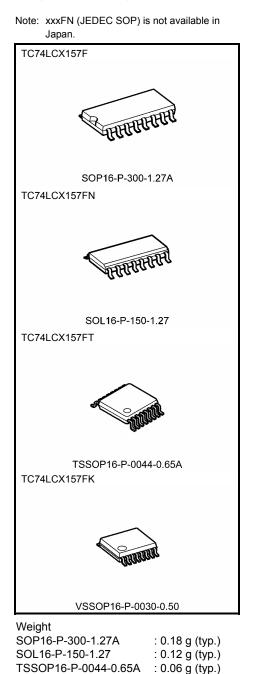
The device is designed for low-voltage $(3.3 \text{ V}) \text{ V}_{CC}$ applications, but it could be used to interface to 5-V supply environment for inputs.

It consists of four 2-input digital multiplexers with common SELECT and \overline{ST} inputs. When the \overline{ST} input is held "H" level, selection of data is inhibited and all the outputs become "L" level. The SELECT decoding determines whether the A or B inputs get routed to their corresponding Y outputs.

All inputs are equipped with protection circuits against static discharge.

Features

- Low-voltage operation: V_{CC} = 2.0 to 3.6 V
- High-speed operation: $t_{pd} = 5.8 \text{ ns} (\text{max}) (V_{CC} = 3.0 \text{ to } 3.6 \text{ V})$
- Ouput current: $|I_{OH}|/I_{OL} = 24 \text{ mA} (\text{min}) (V_{CC} = 3.0 \text{ V})$
- Latch-up performance: -500 mA
- Available in JEDEC SOP, JEITA SOP, TSSOP and VSSOP (US)
- Power-down protection provided on all inputs and outputs
- Pin and function compatible with the 74 series (74AC/VHC/HC/F/ALS/LS etc.) 157 type

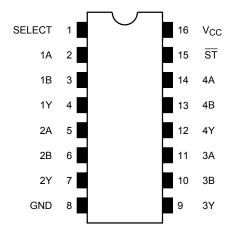


VSSOP16-P-0030-0.50

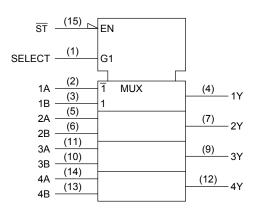
: 0.02 g (typ.)

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Pin Assignment (top view)



IEC Logic Symbol



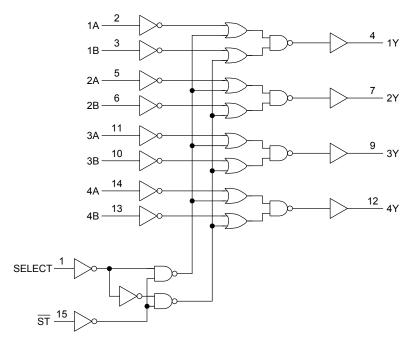
Truth Table

	Outputs			
ST	SELECT A B			Y
Н	Х	Х	Х	L
L	L	L	Х	L
L	L	Н	Х	Н
L	Н	Х	L	L
L	Н	Х	Н	Н

X: Don't care

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System Diagram



Absolute Maximum Ratings (Note 1)

Characteristics	Symbol	Rating	Unit	
Power supply voltage	V _{CC}	-0.5 to 7.0	V	
DC input voltage	V _{IN}	-0.5 to 7.0	V	
		-0.5 to 7.0 (Note 2)	V	
DC output voltage	Vout	-0.5 to V _{CC} + 0.5 (Note 3)		
Input diode current	l _{IK}	-50	mA	
Output diode current	I _{ОК}	±50 (Note 4)	mA	
DC output current	I _{OUT}	±50	mA	
Power dissipation	PD	180	mW	
DC V _{CC} /ground current	I _{CC} /I _{GND}	±100	mA	
Storage temperature	T _{stg}	–65 to 150	°C	

Note 1: Exceeding any of the absolute maximum ratings, even briefly, lead to deterioration in IC performance or even destruction.

Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

Note 2: $V_{CC} = 0 V$

Note 3: High or low state. $I_{\mbox{OUT}}$ absolute maximum rating must be observed.

Note 4: $V_{OUT} < GND, V_{OUT} > V_{CC}$

Operating Ranges (Note 1)

Characteristics	Symbol	Rating	Unit
Power supply voltage	V _{CC}	2.0 to 3.6	
Tower supply voltage	vcc	1.5 to 3.6 (Note 2)	V
Input voltage	V _{IN}	0 to 5.5	V
Output voltage	Vout	0 to 5.5 (Note 3)	V
Output voltage		0 to V _{CC} (Note 4)	v
Output current	Іон/Іог	±24 (Note 5)	mA
Output current	IOH/IOL	±12 (Note 6)	ma
Operating temperature	T _{opr}	-40 to 85	°C
Input rise and fall time	dt/dv	0 to 10 (Note 7)	ns/V

Note 1: The operating ranges must be maintained to ensure the normal operation of the device. Unused inputs must be tied to either VCC or GND.

Note 2: Data retention only

Note 3: $V_{CC} = 0 V$

Note 4: High or low state

Note 5: $V_{CC}=3.0 \mbox{ to } 3.6 \mbox{ V}$

Note 6: $V_{CC} = 2.7$ to 3.0 V

Note 7: $V_{IN}=0.8$ to 2.0 V, $V_{CC}=3.0$ V

Electrical Characteristics

DC Characteristics (Ta = -40 to 85°C)

Characteristics		Symbol	Test Condition		V _{CC} (V)	Min	Max	Unit
	H-level	V _{IH}			2.7 to 3.6	2.0		V
Input voltage	L-level	V _{IL}			2.7 to 3.6		0.8	
		V _{OH}		$I_{OH} = -100 \ \mu A$	2.7 to 3.6	V _{CC} -0.2	_	V
	H-level		$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OH} = -12 \text{ mA}$	2.7	2.2	_	
				I _{OH} = -18 mA	3.0	2.4	_	
Output voltage				$I_{OH} = -24 \text{ mA}$	3.0	2.2	_	
	L-level	V _{OL}	$V_{IN} = V_{IH} \text{ or } V_{IL}$	$I_{OL} = 100 \ \mu A$	2.7 to 3.6	_	0.2	
				$I_{OL} = 12 \text{ mA}$	2.7	_	0.4	
				$I_{OL} = 16 \text{ mA}$	3.0	_	0.4	
				$I_{OL} = 24 \text{ mA}$	3.0	_	0.55	
Input leakage current		lin	V _{IN} = 0 to 5.5 V		2.7 to 3.6	_	±5.0	μA
Power-off leakage current		I _{OFF}	$V_{IN}/V_{OUT} = 5.5 V$		0	—	10.0	μA
Quiescent supply current		Icc	$V_{IN} = V_{CC}$ or GND $V_{IN} = 3.6$ to 5.5 V		2.7 to 3.6	_	10.0	
					2.7 to 3.6	_	±10.0	μA
Increase in Icc per input		∆lcc	$V_{IH} = V_{CC} - 0.6 V$		2.7 to 3.6	_	500	

AC Characteristics (Ta = -40 to 85°C)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Max	Unit
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	6.3	ns
(A, B-Y)	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	5.8	115
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
(SELECT-Y)	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	115
Propagation delay time	t _{pLH}	Figure 1, Figure 2	2.7	_	8.0	ns
(ST -Y)	t _{pHL}		$\textbf{3.3}\pm\textbf{0.3}$	1.5	7.0	115
Output to output skew	t _{osLH}	() -(-)	2.7	_	_	20
	t _{osHL}	(Note)	$\textbf{3.3}\pm\textbf{0.3}$	_	1.0	ns

Note: Parameter guaranteed by design.

 $(t_{osLH} = |t_{pLHm} - t_{pLHn}|, t_{osHL} = |t_{pHLm} - t_{pHLn}|)$

Dynamic Switching Characteristics (Ta = 25°C, input: $t_r = t_f = 2.5$ ns, $C_L = 50$ pF, $R_L = 500 \Omega$)

Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Quiet output maximum dynamic V_{OL}	VOLP	$V_{IH} = 3.3 V, V_{IL} = 0 V$	3.3	0.8	V
Quiet output minimum dynamic V_{OL}	V _{OLV}	$V_{IH} = 3.3 \text{ V}, V_{IL} = 0 \text{ V}$	3.3	0.8	V

Capacitive Characteristics (Ta = 25°C)

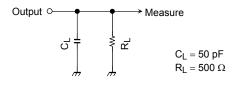
Characteristics	Symbol	Test Condition	V _{CC} (V)	Тур.	Unit
Input capacitance	CIN	_	3.3	7	pF
Output capacitance	C _{OUT}	_	0	8	pF
Power dissipation capacitance	C _{PD}	f _{IN} = 10 MHz (Note)	3.3	25	pF

Note: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:

 $I_{CC (opr)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}$

AC Test Circuit





AC Waveform

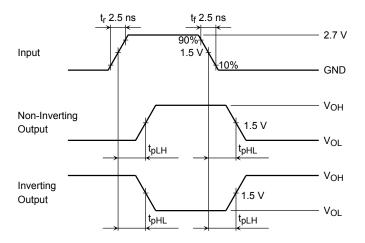
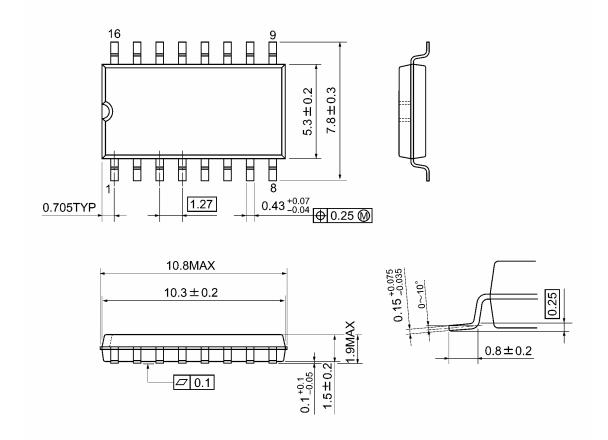


Figure 2 t_{pLH}, t_{pHL}

Package Dimensions

SOP16-P-300-1.27A

Unit: mm

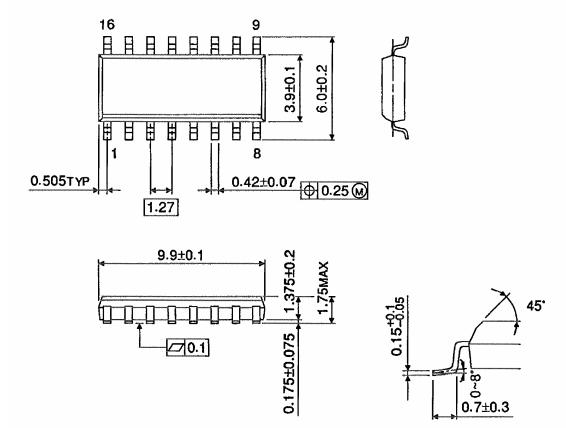


Weight: 0.18 g (typ.)

Package Dimensions (Note)

SOL16-P-150-1.27

Unit : mm



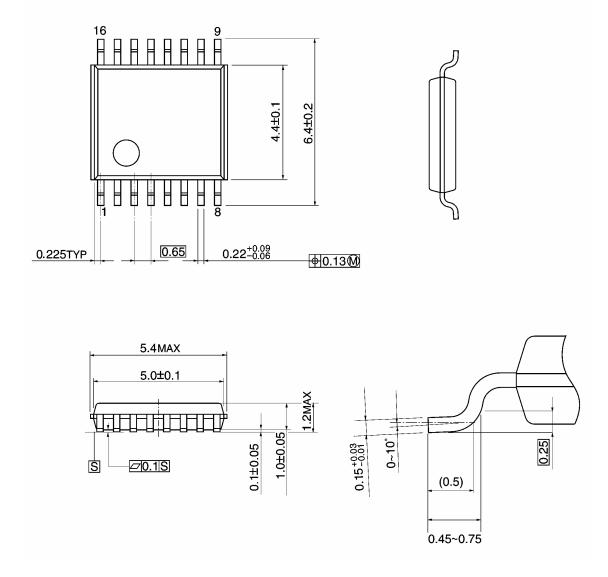
Note: This package is not available in japan.

Weight: 0.12 g (typ.)

Package Dimensions

TSSOP16-P-0044-0.65A

Unit: mm



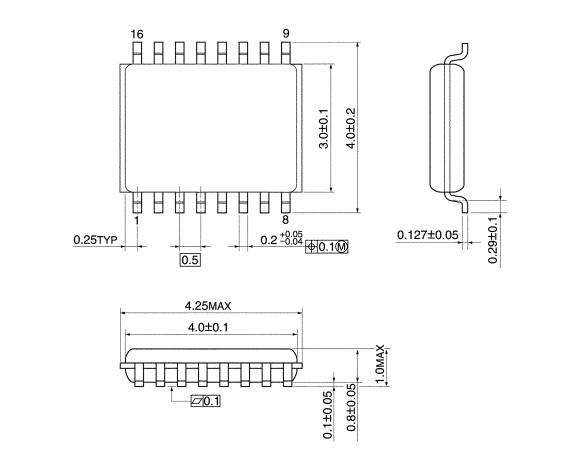
Weight: 0.06 g (typ.)

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Package Dimensions

VSSOP16-P-0030-0.50

Unit: mm



Weight: 0.02 g (typ.)

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20070701-EN GENERAL

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